





"There are spins everywhere" is now a well known quote amongst EMR spectroscopists. It is born out by the huge list of topics at the right hand side. In some of these the use of EMR techniques is obviously minimal, history for example, in others such as biochemistry EMR's influence has been seminal. In topics such as imaging EMR is advancing at a rapid pace, particularly with recent advances in instrumentation and computing power. For at least the next ten years we will see EMR following in the footsteps of NMR in instrumentation - moving to higher field/frequency machinery, and with a move from continuous wave (cw) to fourier transform (ft) measurements, possibly even eclipsing the former in time. This will extend the list of topics even further. Another crumb from the physicist's plate will shortly be available - the use of force balence methods will enable the measurement of single spins on surfaces the ultimate in detection sensitivity. There are also exciting arguments afoot among physicists concerning the very nature of the electron, (New Scientist, 14th October 2000, pp25), Humphrey Maris of Brown University says he thinks he can cut an electron in two! "

- John Maher -

































	Isotope N	uclear Spin (I)	% Abundance
B	¹ H	1/2	99.9
	² H	1	0.02
	12C	0	98.9
ctron Nucleus	13C	1/2	1.1
	¹⁴ N	1	99.6
	15 _N	1/2	0.37
	16O	0	99.8
	17O	5/2	0.037
B - B - B	32S	0	95.0
$D_{eff} = D_0 D_{Ind}$	33S	3/2	0.76
	51V	7/2	99.8
	⁵⁵ M n	5/2	100
	56Fe	0	91.7
	⁵⁷ Fe	1/2	2.19
ctron Nucleus	59Co	7/2	100
ह्यू 🌾	58 _{Ni} & ⁶⁰ Ni	0	68 & 26
	61Ni	3/2	1.19
	63Cu & 65Cu	3/2	69 & 31
	95Mo & 97Mo	5/2	16 & 9
	183W	1/2	14.4















Electron spin – Electron spin Interaction

When there is **more than one unpaired electron** (S>1/2), the interaction between the spins must be considered. This term can be very large. The Hamiltonian for a system with a spin > 1/2 is: $H = D \left[S_z^2 - 1/3 S(S+1) + E/D \left(S_x^2 - S_y^2 \right) \right] + g_0 \beta S H$

The new terms are D and E/D. D is called the zero-field splitting (ZFS) parameter; E/D is the **rhombicity** (the ratio between D, the axial splitting parameter, and E, the rhombic splitting parameter, at zero field). The minimum value of E/D is 0 for an axial system. The maximum value is 1/2 for a rhombic system. The strength of the ZFS is determined by the nature of the ligands.

So for a completely axial system (E/D = 0), $H = D [S_z^2 - 1/3 S(S+1)] + g_o \beta S H$

Consider a case where S = 3/2, i.e., 4 unpaired electrons. These spins can interact to give a total spin moment, referred to as a system spin. There will be four sublevels for m_s , where $S_z = -3/2$, -1/2, 1/2, and 3/2.

The energy for the + or -3/2 level will be: D[9/4-1/3(3/2*5/2)] = D[9/4-5/4] = DThe energy for the + or -1/2 level will be: -D.













a) [07711 (3354 mT)
T m B
M M M M
dentified as \hat{PO}_4^{2-} , \hat{CH}_2OH , \hat{CO}_3^{-} , \hat{SO}_2^{-} , \hat{CO}_3^{3-} , ature. At 113 K \hat{SO}_2^{-} , \hat{CO}_3^{3-} , and \hat{CO}_2^{-} radicals ed neither new species nor detectable effects on e radicals at 113 K is attributed to the freezing of al shows only Mn^{2+} lines, but after γ -irradiation als at ambient temperature, 113 K, in addition to ere determined.

Applications – Diamonds

http://www2.warwick.ac.uk/fac/sci/physics/research/condensedmatt/diamond/

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Applications – Diamonds

The identity of the AB1 and NE4 electron paramagnetic resonance spectra in high-pressure-high-temperature diamond

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1. Introduction

The unique physical properties of diamond and the substantial success of high-pressure-hightemperature (HPHT) synthesis of diamond using transition metal solvertificality ste make this material very strature for numerous applications; from electronic to mechanical purposes. Depending on the growth conditions and the solventification used these synthetic diamond systals continuoris types of numerity-related defect. Inter can significantly after their properties. Therefore, considerableciffort is addressed to identify and characterized after their properties. Therefore, considerableciffort is addressed to identify and characterized after their properties. Therefore, considerableciffort is addressed to identify and characterized after their protection paramagnetic resonance (EPR) centre [1, 2]) or positively charged diamagnetic is take [3], and also in aggregated forms (4 and B aggregates [30]), especially after annealing of the crystals. When Rist Richgs are most as solvent endors. EFR and optical spectra the adjunced lattice interview and expendent on the introgen concentration in the sample. Diamonds with higher introgen content (5.5 pron) exhibits pically optical centres

with zero-phonon lines (ZPLs) at 1.885 and 2.5 eV [4]. Besides, the well known P1 centre and the single substitutional nickel Ni₂, which gives rise to the EPK line at g = 2.0191 (W8 EPK centre with spin S = 372 [5]), are also observed. Turthermore, secretar paramagnetic defects with strong evidence of nickel participation have been found by EPR in recent years [6–15]. Among these centres the AB1–ABK [6–8] and RE-1782 [13] defects are detected in nitrogen-



Figure 4. Prot of the y-values y_1 and y_2 , against the reduced irigonal crystal field (X, i) for a ³ Y_2 state resulting from a d² configuration in a nearly straibedral environment for different orbital quenching factors 1. Contributions from the environ⁴ Fi state and could the ³ $B = ³T_2$ manifold are injered. Appropriate for a single d⁴ finds the peription-the parameter i. Sum ben taken to be regarine.

4. Conclusions

The EPR spectrum of the trigonal NE4 centre, which has been observed in as-grown and annealed synthetic HPHT diamond reystals grown by the split-sphere technique [15] by Nadolinity *et al* [11, 2] yas never detected in as-grown and annealed HPHT diamond samples synthesized at the NRIM [19]. <u>A reaandysis of the publiched data has led as a more accurate</u> determination of the split Hamiltonian parameters describing the anisoteopic distance and a split the split data of the publiched data has led as a more accurate determination of the split Hamiltonian parameters describing than anisoteopic distance and the regular split meteroice could be commony to prior subarco synthesis data the trigonal API centre. Such the API and NE4 centres also corrobustics the proposed assignment of the doublet of lines at 1.72 eV (round by OREER (MCDA) investigations to ABI parameteric data target the proposed models for the ABI (NE4 Centre only the models of a nickel on the centre of the double expression (CVNNCV)² with an d³ tdj) configuration in arigonal divatored strong exclusednal field and a subaritizing ani (red) (Mj, with an associated detect (vacancy or an impurity ion) can explain the experimental g-values.



Applications – Diamonds



Properties, Growth and Applications of Diamond

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